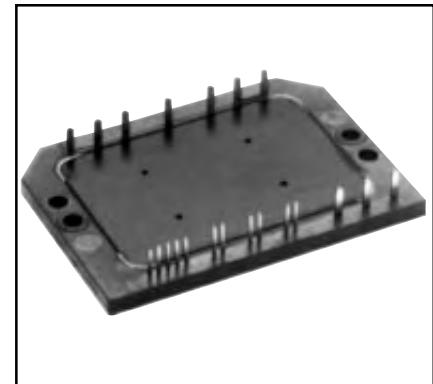
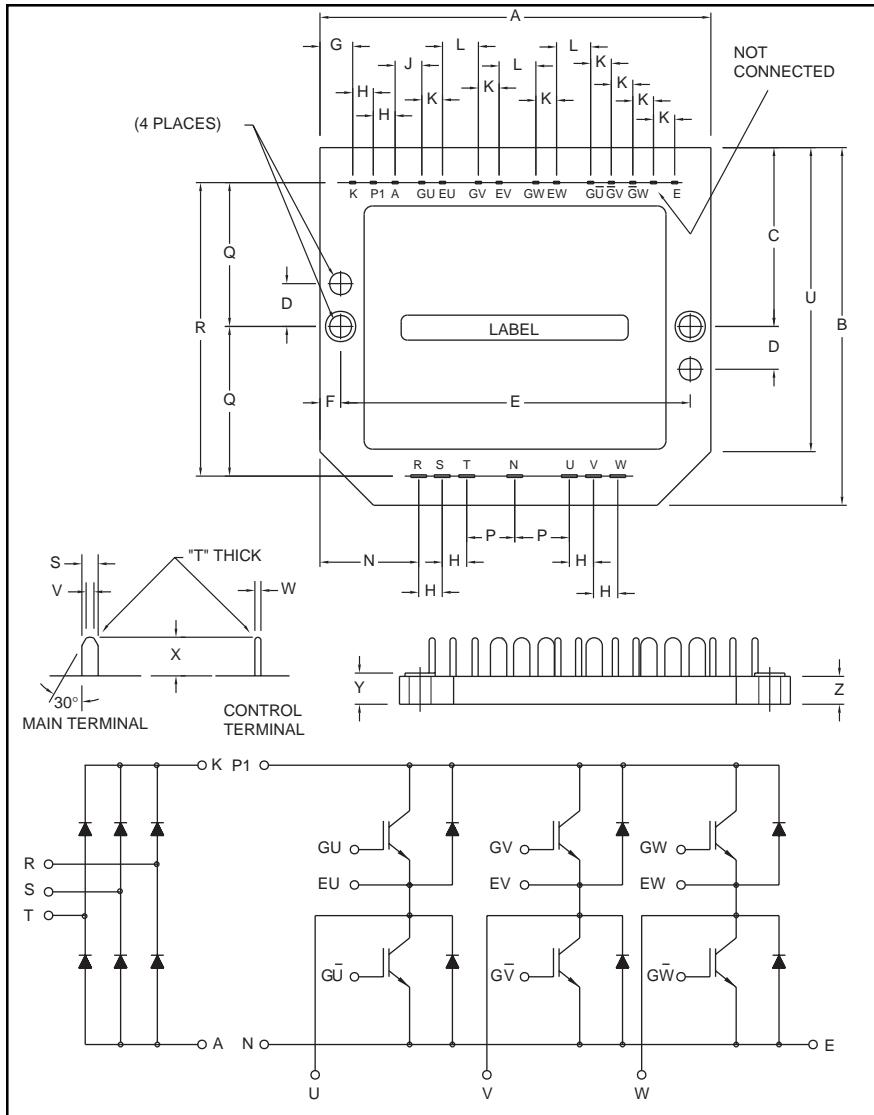


Powerex, Inc., 200 Hillis Street, Youngwood, Pennsylvania 15697-1800 (724) 925-7272

CI Module

**Three Phase Converter +
Three Phase Inverter
15 Amperes/600 Volts**



Description:

Powerex CI Modules are designed for use in switching applications. Each module consists of a three phase diode converter section and a three phase IGBT inverter section. All components and interconnects are isolated from the heat sinking baseplate, offering simplified system assembly and thermal management.

Features:

- Low Drive Power
- Low $V_{CE(sat)}$
- Discrete Super-Fast Recovery (70ns)
- Free-Wheel Diodes
- High Frequency Operation (20-25 kHz)
- Isolated Baseplate for Easy Heat Sinking

Applications:

- AC Motor Control
- Motion/Servo Control
- General Purpose Inverters
- Robotics

Ordering Information:

Example: Select the complete nine digit module part number you desire from the table below - i.e. CM15MD1-12H is a 600V (V_{CES}), 15 Ampere CI Power Module.

| Dimensions | Inches | Millimeters |
|------------|--------|-------------|
| A | 3.54 | 90.0 |
| B | 2.52 | 64.0 |
| C | 1.26 | 32.0 |
| D | 0.35 | 9.0 |
| E | 3.15 | 80.0 |
| F | 0.20 | 5.0 |
| G | 0.30 | 7.5 |
| H | 0.32 | 8.0 |
| J | 0.48 | 12.28 |
| K | 0.10 | 2.54 |
| L | 0.30 | 7.62 |
| M | 0.19 | 4.8 |

| Dimensions | Inches | Millimeters |
|------------|--------|-------------|
| N | 0.65 | 16.5 |
| P | 0.49 | 12.5 |
| Q | 1.04 | 26.5 |
| R | 2.09 | 53.0 |
| S | 0.08 | 2.0 |
| T | 0.02 | 0.5 |
| U | 2.13 | 54.0 |
| V | 0.04 | 1.0 |
| W | 0.03 | 0.8 |
| X | 0.32 | 8.0 |
| Y | 0.21 | 5.3 |
| Z | 0.20 | 5.0 |

| Type | Current Rating Amperes | V_{CES} Volts (x 50) |
|------|---------------------------|---------------------------|
| CM | 15 | 12 |



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CM15MD1-12H

CI Module

Three Phase Converter + Three Phase Inverter

15 Amperes/600 Volts

Absolute Maximum Ratings, $T_j = 25^\circ\text{C}$ unless otherwise specified

| Characteristics | Symbol | CM15MD1-12H | Units |
|--|-----------|-------------|----------------------|
| Power Device Junction Temperature | T_j | -40 to 150 | °C |
| Storage Temperature | T_{stg} | -40 to 125 | °C |
| Mounting Torque, M4 Mounting Screws | — | 13 | in-lb |
| Module Weight (Typical) | — | 60 | Grams |
| Isolation Voltage, AC 1 minute, 60Hz | V_{RMS} | 2500 | Volts |
| Converter Part | | | |
| Repetitive Peak Reverse Voltage | V_{RRM} | 800 | Volts |
| Recommended AC Input Voltage | E_a | 220 | Volts |
| DC Output Current | I_O | 20 | Amperes |
| Surge (Non-repetitive) Forward Current | I_{FSM} | 300 | Amperes |
| I^2t for Fusing | I^2t | 375 | A^2s |
| IGBT Inverter Part | | | |
| Collector-Emitter Voltage (G-E Short) | V_{CES} | 600 | Volts |
| Gate-Emitter Voltage (C-E Short) | V_{GES} | ± 20 | Volts |
| Collector Current | I_C | 15 | Amperes |
| Collector Current (Pulse)* | I_{CM} | 30 | Amperes |
| Emitter Current** | I_E | 15 | Amperes |
| Emitter Current** (Pulse)* | I_{EM} | 30 | Amperes |
| Maximum Collector Dissipation | P_C | 45 | Watts |

Electrical and Mechanical Characteristics, $T_j = 25^\circ\text{C}$ unless otherwise specified

| Characteristics | Symbol | Test Conditions | Min. | Typ. | Max. | Units |
|--------------------------------------|---------------------|--|---|------|------|---------------|
| Converter Sector | | | | | | |
| Repetitive Reverse Current | I_{RRM} | $V_R = V_{RRM}, T_j = 150^\circ\text{C}$ | — | — | 8 | mA |
| Forward Voltage Drop | V_{FM} | $I_F = 20\text{A}$ | — | — | 1.5 | Volts |
| Thermal Resistance (Junction-to-Fin) | $R_{th(j-f)}$ | Per Diode | — | — | 3.6 | °C/W |
| IGBT Inverter Sector | | | | | | |
| Collector Cutoff Current | I_{CES} | $V_{CE} = V_{CES}, V_{GE} = 0\text{V}$ | — | — | 1 | mA |
| Gate-Emitter Threshold Voltage | $V_{GE(th)}$ | $V_{CE} = 10\text{V}, I_C = 1.5\text{mA}$ | 4.5 | 6.0 | 7.5 | Volts |
| Gate-Emitter Cutoff Current | I_{GES} | $V_{GE} = V_{GES}, V_{CE} = 0\text{V}$ | — | — | 0.5 | μA |
| Collector-Emitter Saturation Voltage | $V_{CE(sat)}$ | $V_{GE} = 15\text{V}, I_C = 15\text{A}, T_j = 25^\circ\text{C}$ | — | 2.1 | 2.8 | Volts |
| | | $V_{GE} = 15\text{V}, I_C = 15\text{A}, T_j = 150^\circ\text{C}$ | — | 2.15 | — | Volts |
| Input Capacitance | C_{ies} | | — | — | 1.5 | nF |
| Output Capacitance | C_{oes} | $V_{GE} = 0\text{V}, V_{CE} = 10\text{V}$ | — | — | 1.2 | nF |
| Reverse Transfer Capacitance | C_{res} | | — | — | 0.3 | nF |
| Total Gate Charge | Q_G | $V_{CC} = 300\text{V}, I_C = 15\text{A}, V_{GE} = 15\text{V}$ | — | 45 | — | nC |
| Resistive Load | Turn-on Delay Time | $t_{d(on)}$ | $V_{GE1} = V_{GE2} = 15\text{V},$ | — | — | nS |
| | Rise Time | t_r | $V_{CC} = 300\text{V}, I_C = 15\text{A},$ | — | — | nS |
| Switching Times | Turn-off Delay Time | $t_{d(off)}$ | $R_g = 42\Omega,$ | — | — | nS |
| | Fall Time | t_f | Resistive Load | — | — | nS |
| Emitter-Collector Voltage | V_{EC} | $I_E = 15\text{A}, V_{GE} = 0\text{V}$ | — | — | 2.8 | Volts |
| Reverse Recovery Time | t_{rr} | $I_E = 15\text{A}, V_{GE} = 0\text{V},$ | — | — | 110 | nS |
| Reverse Recovery Charge | Q_{rr} | $dI_E/dt = -30\text{A}/\mu\text{s}$ | — | 0.04 | — | μC |
| Thermal Resistance (Junction-to-Fin) | $R_{th(j-f)}$ | Per IGBT | — | — | 2.8 | °C/W |
| | | Per FWDi | — | — | 3.5 | °C/W |

*Pulse width and repetition rate should be such that device junction temperature does not exceed maximum rating.

**Characteristics of the anti-parallel emitter-collector free-wheel diode.